LMH6574 4:1 High Speed Video Multiplexer

Check for Samples: LMH6574

FEATURES

- **500 MHz, 500 mV −3 dB Bandwidth, A_V = 2**
- **400 MHz, 2V_{PP} −3 dB Bandwidth, A_V = 2**
- **8 ns Channel Switching Time**
- **70 dB Channel to Channel Isolation @ 10 MHz**
- **0.02%, 0.05° Diff. Gain, Phase**
- **0.1 dB Gain Flatness to 150 MHz**
- **2200 V/µs Slew Rate**
- **Wide Supply Voltage Range: 6V (±3V) to 12V (±6V)**
- **-68 dB HD2 @ 5 MHz**
- **-84 dB HD3 @ 5 MHz**

APPLICATIONS

- **Video Router**
- **Multi Input Video Monitor**
- **Instrumentation/Test Equipment**
- **Receiver IF Diversity Switch**
- **Multi Channel A/D Driver**
- **Picture in Picture Video Switch**

DESCRIPTION

The LMH™ 6574 is a high performance analog multiplexer optimized for professional grade video and other high fidelity high bandwidth analog applications. The output amplifier selects any one of four buffered input signals based on the state of the two address bits. The LMH6574 provides a 400 MHz bandwidth at 2 V_{PP} output signal levels. Multimedia and high definition television (HDTV) applications can benefit from the LMH6574's 0.1 dB bandwidth of 150 MHz and its 2200 V/µs slew rate.

The LMH6574 supports composite video applications with its 0.02% and 0.05° differential gain and phase errors for NTSC and PAL video signals while driving a single, back terminated 75Ω load. An 80 mA linear output current is available for driving multiple video load applications.

The LMH6574 gain is set by external feedback and gain set resistors for maximum flexibility.

The LMH6574 is available in the 14 pin SOIC package.

Connection Diagram

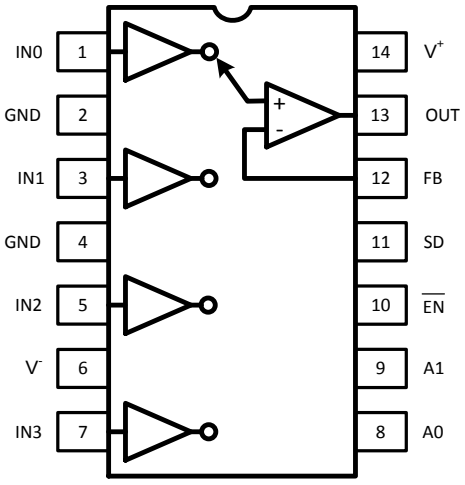


Figure 1. 14-Pin SOIC (Top View)

Truth Table

A1	A0	$\overline{EN}$	SD	OUT
1	1	0	0	CH 3
1	0	0	0	CH2
0	1	0	0	CH1
0	0	0	0	CH 0
X	X	1	0	Disable
X	X	X	1	Shutdown

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings(1)(2)

ESD Tolerance(3)	Human Body Model	2000V
	Machine Model	200V
Supply Voltage ($V^+ - V^-$)		13.2V
I_{OUT}(4)		130 mA
Signal & Logic Input Pin Voltage		±(V_S+0.6V)
Signal & Logic Input Pin Current		±20 mA
Maximum Junction Temperature		+150°C
Storage Temperature Range		−65°C to +150°C
Soldering Information	Infrared or Convection (20 sec)	235 °C
	Wave Soldering (10 sec)	260 °C

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications, see the Electrical Characteristics tables.
(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
(3) Human Body model, 1.5 kΩ in series with 100 pF. Machine model, 0Ω In series with 200 pF.
(4) The maximum output current (I_{OUT}) is determined by the device power dissipation limitations (The junction temperature cannot be allowed to exceed 150°C). See the POWER DISSIPATION section for more details. A short circuit condition should be limited to 5 seconds or less.

Operating Ratings(1)

Operating Temperature			−40 °C to 85 °C
Supply Voltage Range			6V to 12V
Thermal Resistance			
Package	14-Pin SOIC	(θ_{JA})	130°C/W
		(θ_{JC})	40°C/W

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications, see the Electrical Characteristics tables.

±5V Electrical Characteristics

V_S = ±5V, R_L = 100Ω, A_V = 2 V/V, R_F = 575 Ω, T_J = 25 °C, Unless otherwise specified. **Bold** numbers specify limits at temperature extremes.

Symbol	Parameter	Conditions[1]	Min	Typ	Max	Units
Frequency Domain Performance						
SSBW	−3 dB Bandwidth	V_{OUT} = 0.5 V_{PP}		500		MHz
LSBW	–3 dB Bandwidth	V_{OUT} = 2 V_{PP}		400		MHz
.1 dBBW	0.1 dB Bandwidth	V_{OUT} = 0.25 V_{PP}		150		MHz
DG	Differential Gain	R_L = 150Ω, f = 4.43 MHz		0.02		%
DP	Differential Phase	R_L = 150Ω, f = 4.43MHz		0.05		deg
XTLK	Channel to Channel Crosstalk	All Hostile, 5 MHz		−85		dB
Time Domain Response						
TRS	Channel to Channel Switching Time	Logic Transition to 90% Output		8		ns
	Enable and Disable Times	Logic Transition to 90% or 10% Output		10		ns
TRL	Rise and Fall Time	4V Step		2.4		ns
TSS	Settling Time to 0.05%	2V Step		17		ns
OS	Overshoot	2V Step		5		%
SR	Slew Rate	4V Step		2200		V/µs
Distortion						
HD2	2nd Harmonic Distortion	2 V_{PP} , 5 MHz		−68		dBc
HD3	3rd Harmonic Distortion	2 V_{PP} , 5 MHz		−84		dBc
IMD	3rd Order Intermodulation Products	10 MHz, Two Tones 2 V_{PP} at Output		−80		dBc
Equivalent Input Noise						
VN	Voltage	>1 MHz, Input Referred		5		nV/√Hz
ICN	Current	>1 MHz, Input Referred		5		pA/√Hz
Static, DC Performance						
CHGM	Channel to Channel Gain Difference	DC, Difference in Gain Between Channels		±0.005	±0.032 **±0.035**	%
VIO	Input Offset Voltage[2]	V_{IN} = 0V		1	±20 **±25**	mV
DVIO	Offset Voltage Drift			30		µV/°C
IBN	Input Bias Current[2][3]	V_{IN} = 0V		−3	±5 **±5.6**	µA
DIBN	Bias Current Drift			11		nA/°C
	Inverting Input Bias Current	Pin 12, Feedback Point, V_{IN} = 0V		−7	±10 **±13**	
PSRR	Power Supply Rejection Ratio[2]	DC, Input Referred	47 **45**	54		dB
ICC	Supply Current[2]	No Load		13	16 **18**	mA
	Supply Current Disabled[2]	$\overline{\text{ENABLE}}$>2V		4.7	5.8 **5.9**	mA
	Supply Current Shutdown	SHUTDOWN > 2V		1.8	2.5 **2.6**	mA
VIH	Logic High Threshold[2]	Select & Enable Pins (SD & $\overline{\text{EN}}$)	2.0			V
VIL	Logic Low Threshold[2]	Select & Enable Pins (SD & $\overline{\text{EN}}$)			0.8	V
IiL	Logic Pin Input Current Low[3]	Logic Input = 0V Select & Enable Pins (SD & $\overline{\text{EN}}$)	−2.9 **-8.5**	−1		µA

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No ensure of parametric performance is indicated in the electrical tables under conditions of internal self heating where $T_J > T_A$. See Application Notes for information on temperature de-rating of this device. Min/Max ratings are based on product testing, characterization and simulation. Individual parameters are tested as noted.
(2) Parameters ensured by electrical testing at 25°C.
(3) Positive Value is current into device.

±5V Electrical Characteristics (continued)

V_S = ±5V, R_L = 100Ω, A_V = 2 V/V, R_F = 575 Ω, T_J = 25 °C, Unless otherwise specified. **Bold** numbers specify limits at temperature extremes.

Symbol	Parameter	Conditions[1]	Min	Typ	Max	Units
IiH	Logic Pin Input Current High[3]	Logic Input = 2.0V, Select & Enable Pins (SD & $\overline{EN}$)		47	68 **72.5**	µA
Miscellaneous Performance						
RIN+	Input Resistance			5		kΩ
CIN	Input Capacitance			0.8		pF
ROUT	Output Resistance	Output Active, ($\overline{EN}$ and SD < 0.8 V)		0.04		Ω
ROUT	Output Resistance	Output Disabled, ($\overline{EN}$ or SD > 2V)		3000		Ω
COUT	Output Capacitance	Output Disabled, ($\overline{EN}$ or SD > 2V)		3.1		pF
VO	Output Voltage Range	No Load	±3.54 **±3.53**	±3.7		V
VOL		R_L = 100Ω	±3.18 **±3.17**	±3.5		V
CMIR	Input Voltage Range		±2.5	±2.6		V
IO	Linear Output Current[2][3]	V_{IN} = 0V	+60 -70 **+50** **−60**	±80		mA
ISC	Short Circuit Current[4]	V_{IN} = ±2V, Output Shorted to Ground		±230		mA

(4) The maximum output current (I_{OUT}) is determined by the device power dissipation limitations (The junction temperature cannot be allowed to exceed 150°C). See the POWER DISSIPATION section for more details. A short circuit condition should be limited to 5 seconds or less.

±3.3V Electrical Characteristics

V_S = ±3.3V, R_L = 100Ω, A_V = 2 V/V, R_F = 575 Ω; Unless otherwise specified.

Symbol	Parameter	Conditions[1]	Min	Typ	Max	Units
Frequency Domain Performance						
SSBW	−3 dB Bandwidth	V_{OUT} = 0.5 V_{PP}		475		MHz
LSBW	−3 dB Bandwidth	V_{OUT} = 2.0 V_{PP}		375		MHz
0.1 dBBW	0.1 dB Bandwidth	V_{OUT} = 0.5 V_{PP}		100		MHz
GFP	Peaking	DC to 200 MHz		0.4		dB
XTLK	Channel to Channel Crosstalk	All Hostile, f = 5 MHz		−85		dBc
Time Domain Response						
TRL	Rise and Fall Time	2V Step		2		ns
TSS	Settling Time to 0.05%	2V Step		20		ns
OS	Overshoot	2V Step		5		%
SR	Slew Rate	2V Step		1400		V/µs
Distortion						
HD2	2nd Harmonic Distortion	2 V_{PP}, 10 MHz		−67		dBc
HD3	3rd Harmonic Distortion	2 V_{PP}, 10 MHz		−87		dBc
Static, DC Performance						
VIO	Input Offset Voltage	V_{IN} = 0V		-5		mV
IBN	Input Bias Current[2]	V_{IN} = 0V		-3		µA
PSRR	Power Supply Rejection Ratio	DC, Input Referred		49		dB
ICC	Supply Current	No Load		12		mA
VIH	Logic High Threshold	Select & Enable Pins (SD & $\overline{EN}$)	1.3			V
VIL	Logic Low Threshold	Select & Enable Pins (SD & $\overline{EN}$)			0.4	V
Miscellaneous Performance						
RIN+	Input Resistance			5		kΩ
CIN	Input Capacitance			0.8		pF
ROUT	Output Resistance			0.06		Ω
VO	Output Voltage Range	No Load		±2		V
VOL		R_L = 100Ω		±1.8		V
CMIR	Input Voltage Range			±1.2		V
IO	Linear Output Current	V_{IN} = 0V		±60		mA
ISC	Short Circuit Current	V_{IN} = ±1V, Output Shorted to Ground		±150		mA

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No ensure of parametric performance is indicated in the electrical tables under conditions of internal self heating where $T_J > T_A$. See Application Notes for information on temperature de-rating of this device. Min/Max ratings are based on product testing, characterization and simulation. Individual parameters are tested as noted.

(2) Positive Value is current into device.

Typical Performance Characteristics

V_s = ±5V, R_L = 100Ω, A_V = 2, R_F = R_G = 575Ω; unless otherwise specified.

Frequency Response vs. V_{OUT}

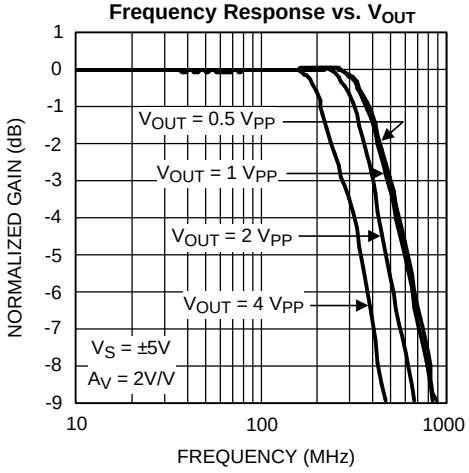


Figure 2.

Frequency Response vs. Gain

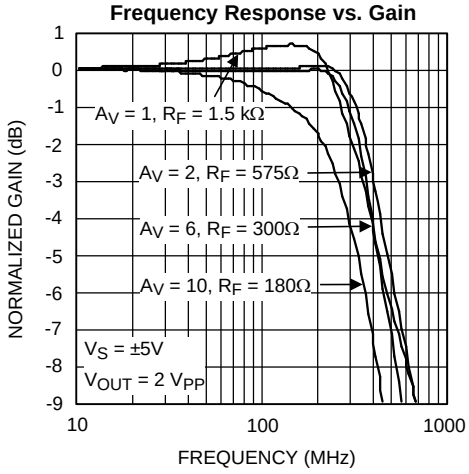


Figure 3.

Frequency Response vs. Capacitive Load

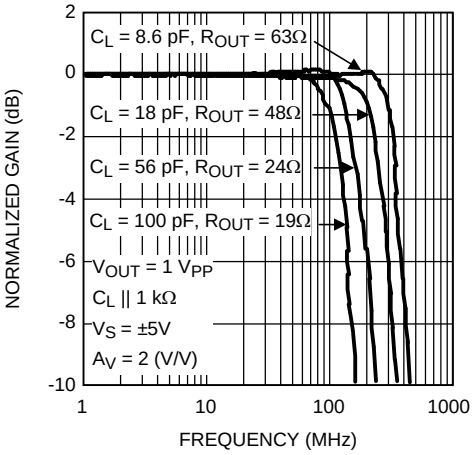


Figure 4.

Suggested R_{OUT} vs. Capacitive Load

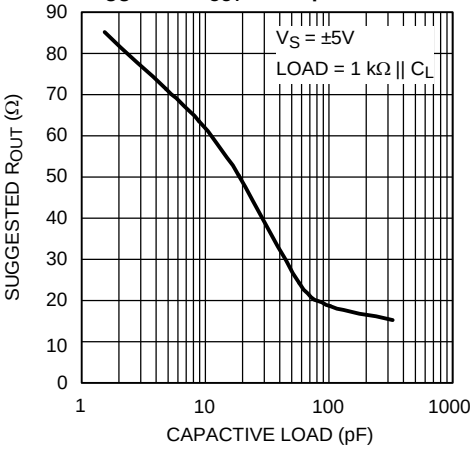


Figure 5.

Suggested Value of R_F vs. Gain

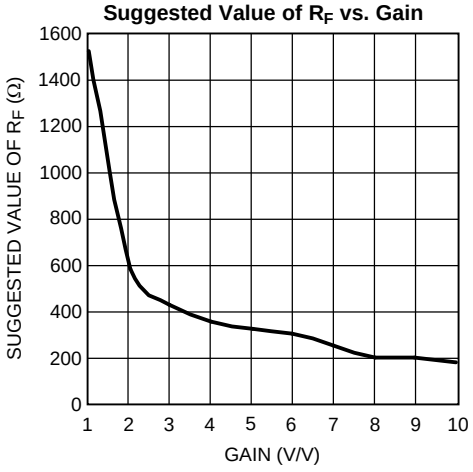


Figure 6.

Pulse Response 4V_{PP}

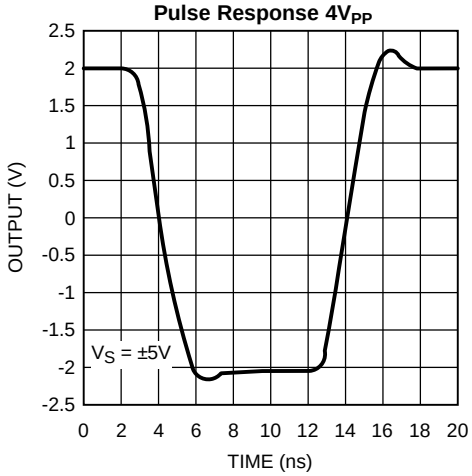


Figure 7.

Typical Performance Characteristics (continued)

V_s = ±5V, R_L = 100Ω, A_V = 2, R_F = R_G = 575Ω; unless otherwise specified.

Pulse Response $2V_{PP}$

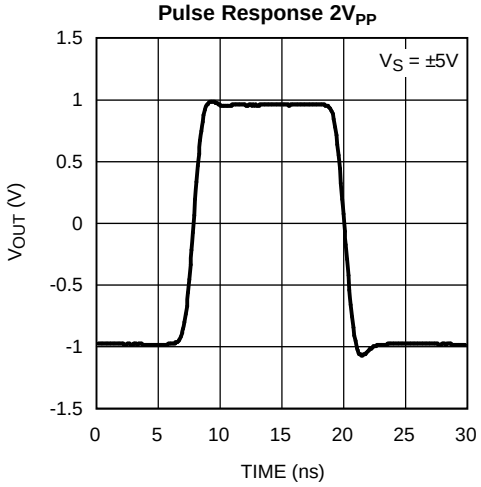


Figure 8.

Pulse Response $2V_{PP}$

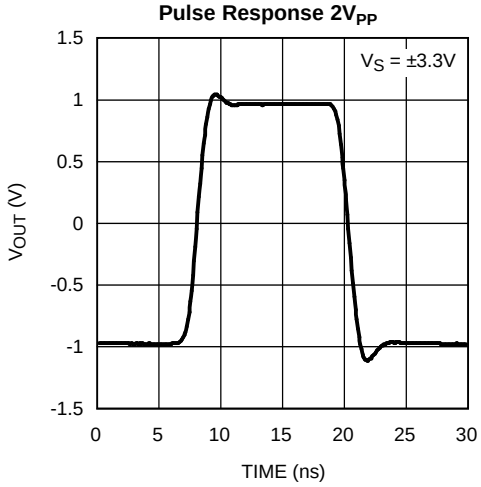


Figure 9.

Closed Loop Output Impedance

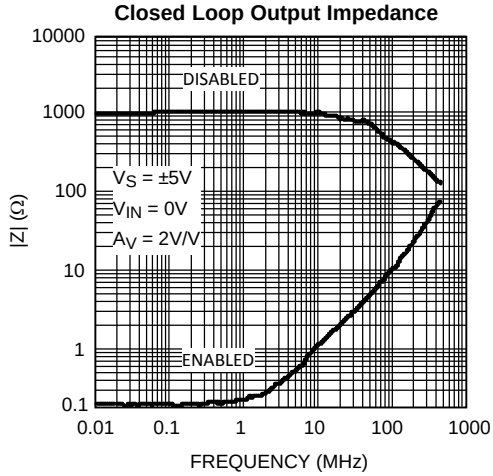


Figure 10.

Closed Loop Output Impedance

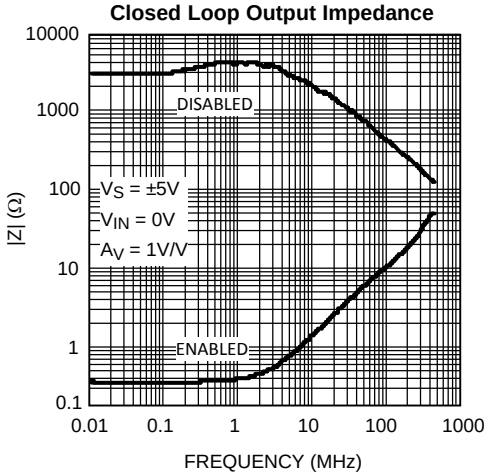


Figure 11.

PSRR vs. Frequency

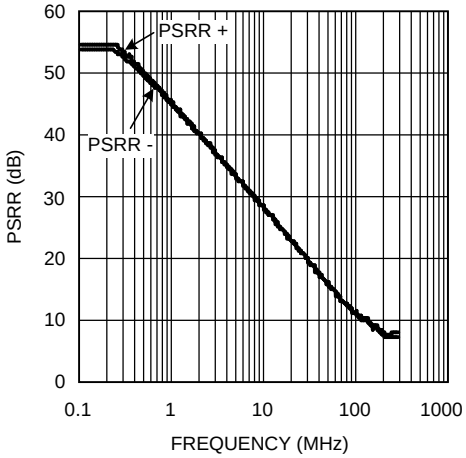


Figure 12.

Channel Switching

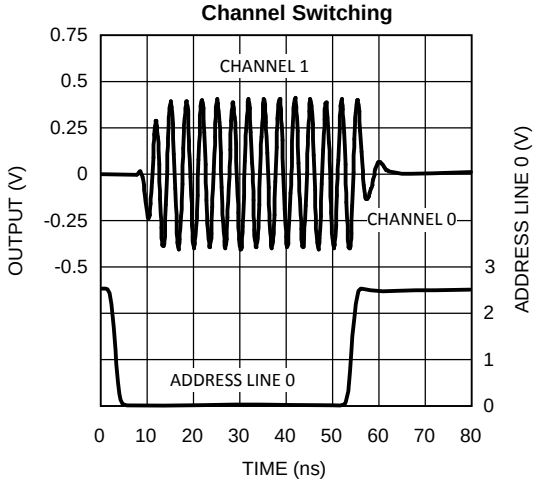


Figure 13.

Typical Performance Characteristics (continued)

V_s = ±5V, R_L = 100Ω, A_V = 2, R_F = R_G = 575Ω; unless otherwise specified.

SHUTDOWN Switching

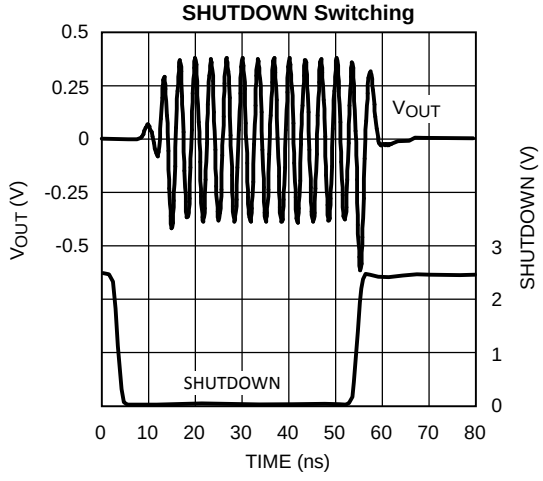


Figure 14.

Shutdown Glitch

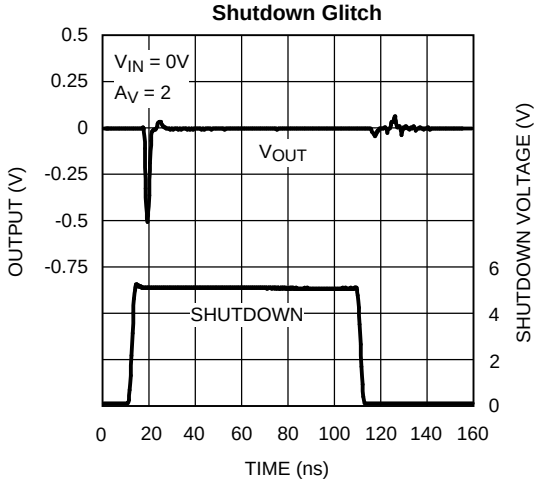


Figure 15.

$\overline{\text{ENABLE}}$ Switching

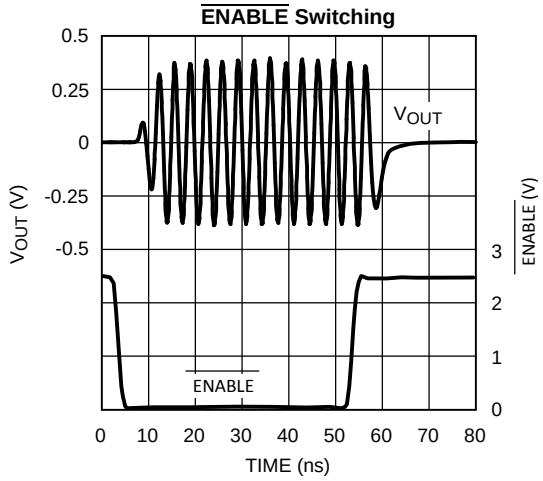


Figure 16.

Disable Glitch

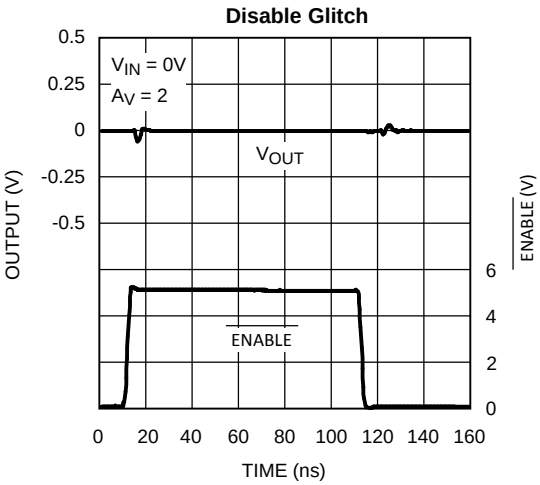


Figure 17.

HD2 vs. Frequency

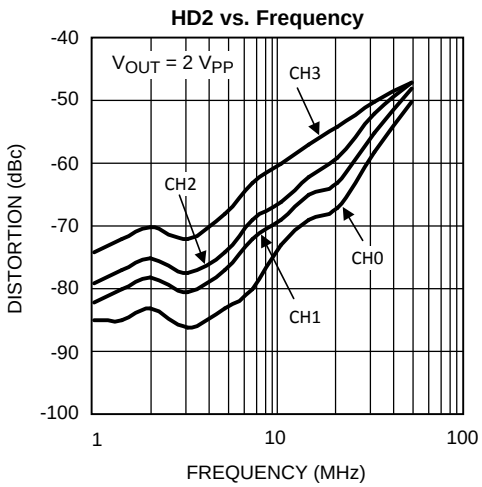


Figure 18.

HD3 vs. Frequency

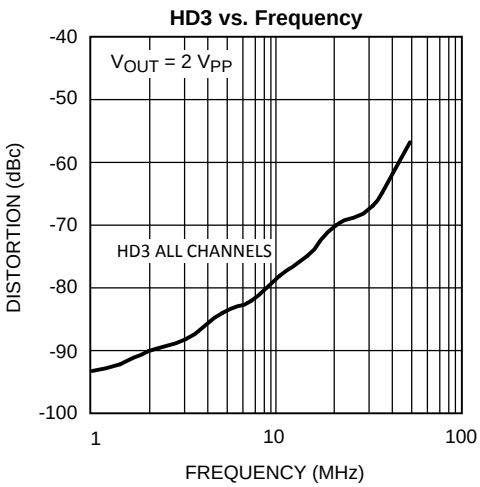


Figure 19.

Typical Performance Characteristics (continued)

V_s = ±5V, R_L = 100Ω, A_V = 2, R_F = R_G = 575Ω; unless otherwise specified.

HD2 vs. V_S

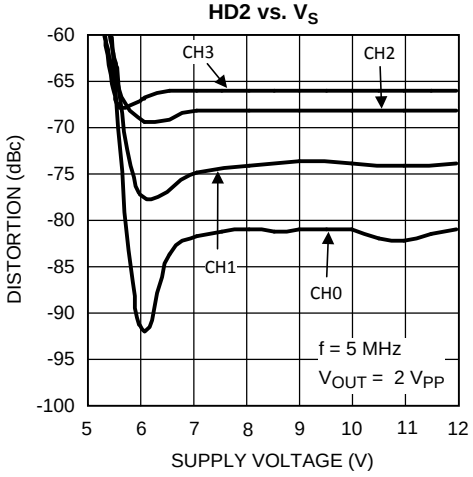


Figure 20.

HD3 vs. V_S

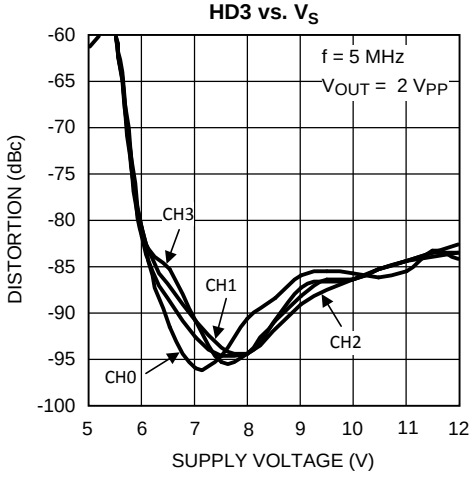


Figure 21.

HD2 vs. V_{OUT}

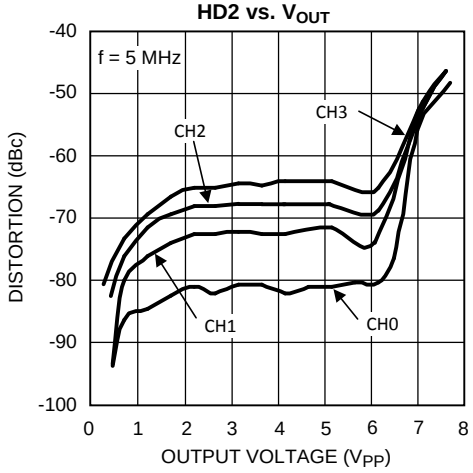


Figure 22.

HD3 vs. V_{OUT}

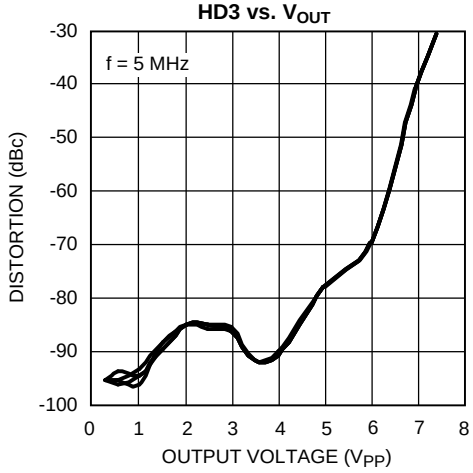


Figure 23.

Minimum V_{OUT} vs. I_{OUT} (1)

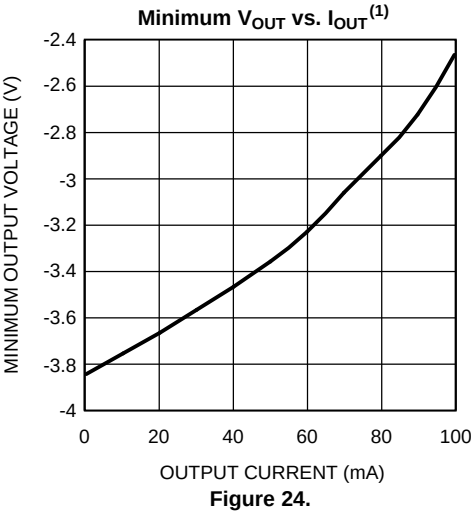


Figure 24.

Maximum V_{OUT} vs. I_{OUT} (1)

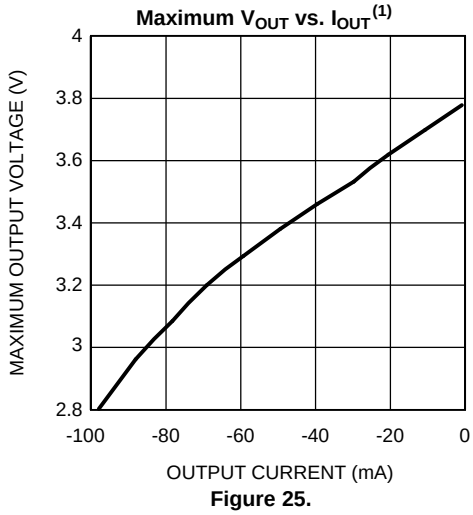


Figure 25.

(1) Positive Value is current into device.

Typical Performance Characteristics (continued)

V_s = ±5V, R_L = 100Ω, A_V = 2, R_F = R_G = 575Ω; unless otherwise specified.

Crosstalk vs. Frequency

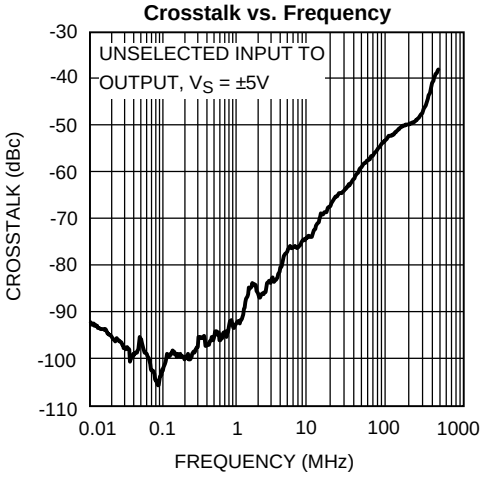


Figure 26.

Off Isolation

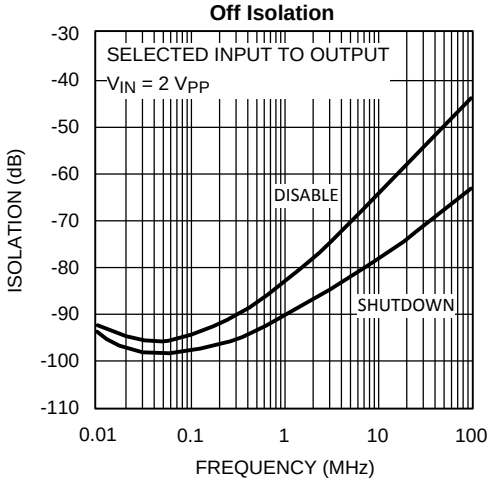


Figure 27.

APPLICATION NOTES

GENERAL INFORMATION

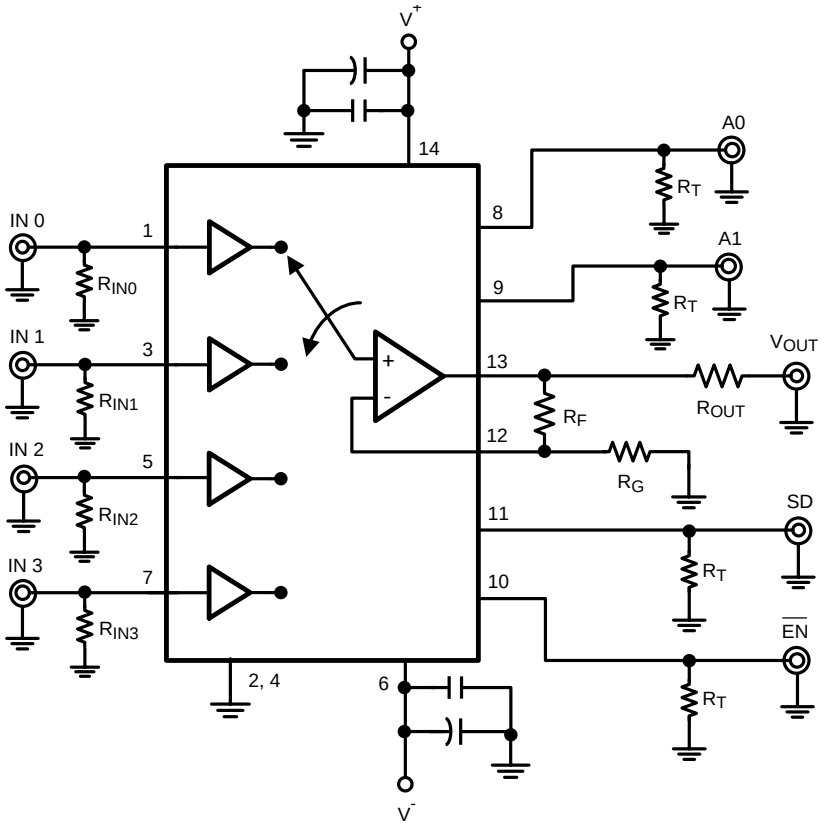


Figure 28. Typical Application

The LMH6574 is a high-speed 4:1 analog multiplexer, optimized for very high speed and low distortion. With selectable gain and excellent AC performance, the LMH6574 is ideally suited for switching high resolution, presentation grade video signals. The LMH6574 has no internal ground reference. Single or split supply configurations are both possible. The LMH6574 features very high speed channel switching and disable times. When disabled the LMH6574 output is high impedance making MUX expansion possible by combining multiple devices. See MULTIPLEXER EXPANSION below.

VIDEO PERFORMANCE

The LMH6574 has been designed to provide excellent performance with production quality video signals in a wide variety of formats such as HDTV and High Resolution VGA. Best performance will be obtained with back-terminated loads. The back termination reduces reflections from the transmission line and effectively masks transmission line and other parasitic capacitances from the amplifier output stage. Figure 28 shows a typical configuration for driving a 75Ω. Cable. The output buffer is configured for a gain of 2, so using back terminated loads will give a net gain of 1.

FEEDBACK RESISTOR SELECTION

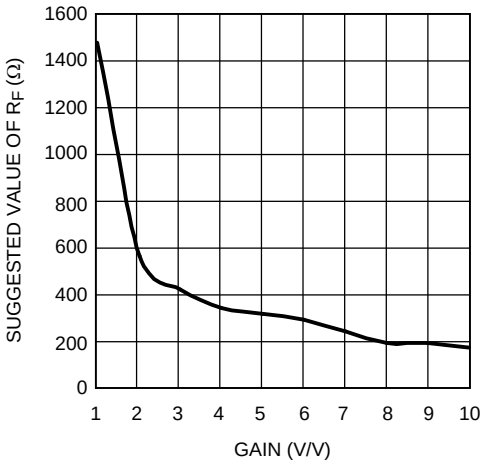


Figure 29. Suggested R_F vs. Gain

The LMH6574 has a current feedback output buffer with gain determined by external feedback (R_F) and gain set (R_G) resistors. With current feedback amplifiers, the closed loop frequency response is a function of R_F. For a gain of 2 V/V, the recommended value of R_F is 575Ω. For other gains see Figure 29. Generally, lowering R_F from the recommended value will peak the frequency response and extend the bandwidth while increasing the value of R_F will cause the frequency response to roll off faster. Reducing the value of R_F too far below the recommended value will cause overshoot, ringing and, eventually, oscillation.

Since all applications are slightly different it is worth some experimentation to find the optimal R_F for a given circuit. For more information see Application Note OA-13 (SNOA366) which describes the relationship between R_F and closed-loop frequency response for current feedback operational amplifiers. The impedance looking into pin 12 is approximately 20Ω. This allows for good bandwidth at gains up to 10 V/V. When used with gains over 10 V/V, the LMH6574 will exhibit a “gain bandwidth product” similar to a typical voltage feedback amplifier. For gains of over 10 V/V consider selecting a high performance video amplifier like the LMH6720 to provide additional gain.

SD vs. $\overline{EN}$

The LMH6574 has both shutdown and disable capability. The shutdown feature affects the entire chip, whereas the disable function only affects the output buffer. When in shutdown mode, minimal power is consumed. The shutdown function is very fast, but causes a very brief spike of about 400 mV to appear on the output. When in shutdown mode the LMH6574 consumes only 1.8 mA of supply current. For maximum input to output isolation use the shutdown function.

The $\overline{EN}$ pin only disables the output buffer which results in a substantially reduced output glitch of only 50 mV. While disabled the chip consumes 4.7 mA, considerably more than when shutdown. This is because the input buffers are still active. For minimal output glitch use the $\overline{EN}$ pin. Also, care should be taken to ensure that, while in the disabled state, the voltage differential between the active input buffer (the one selected by pins A0 and A1) and the output pin stays less than 2V. As the voltage differential increases, input to output isolation decreases. Normally this is not an issue. See the section on MULTIPLEXER EXPANSION for further details.

To reduce the output glitch when using the SD pin, switch the $\overline{EN}$ pin at least 10 ns before switching the SD pin. This can be accomplished by using an RC delay circuit between the two pins if only one control signal is available.

Logic inputs "SD" and "$\overline{EN}$" will revert to the "High", while "A_0" and "A_1" will revert to the "Low" state when left floating.

MULTIPLEXER EXPANSION

Figure 30 shows an 8:1 MUX using two LMH6574s.

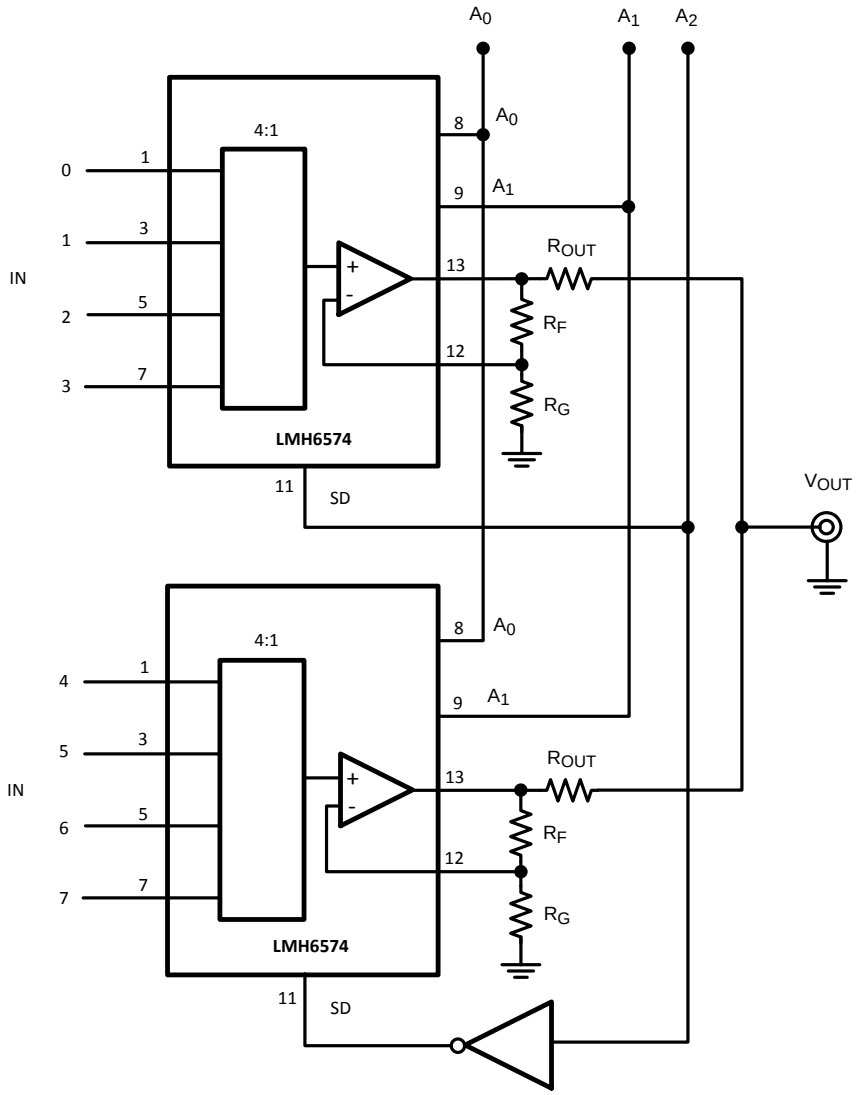


Figure 30. 8:1 MUX USING TWO LMH6574s

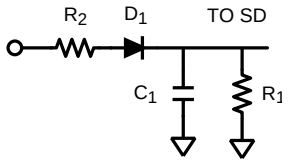


Figure 31. Delay Circuit Implementation

If it is important in the end application to make sure that no two inputs are presented to the output at the same time, an optional delay block can be added, to drive the SHUTDOWN pin of each device. Figure 31 shows one possible approach to this delay circuit. The delay circuit shown will delay SHUTDOWN's H to L transitions (R_1 and C_1 decay) but won't delay its L to H transition. R_2 should be kept small compared to R_1 in order to not reduce the SHUTDOWN voltage and to produce little or no delay to SHUTDOWN.

With the SHUTDOWN pin putting the output stage into a high impedance state, several LMH6574's can be tied together to form a larger input MUX. However, there is a loading effect on the active output caused by the unselected devices. The circuit in Figure 32 shows how to compensate for this effect. For the 16:1 MUX function shown in Figure 32 below the gain error would be about −0.8 dB, or about 9%. In the circuit in Figure 32, resistor ratios have been adjusted to compensate for this gain error. By adjusting the gain of each multiplexer circuit the error can be reduced to the tolerance of the resistors used (1% in this example).

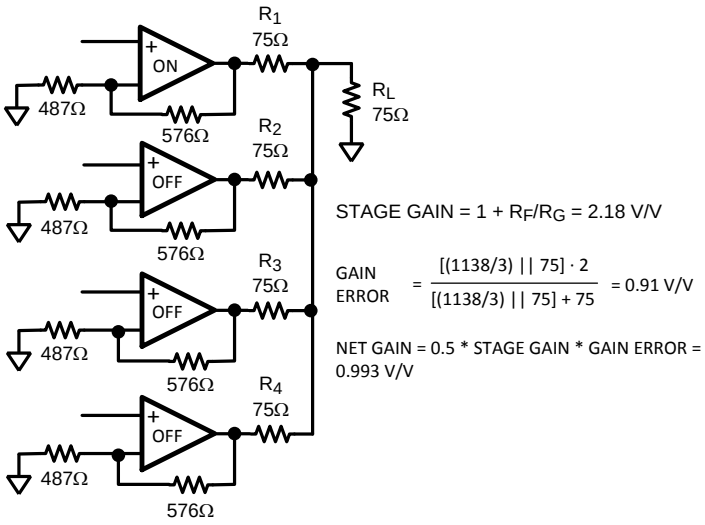


Figure 32. Multiplexer Gain Compensation

Disabling of the LMH6574 using the $\overline{EN}$ pin is not recommended for use when doing multiplexer expansion. While disabled, If the voltage between the selected input and the chip output exceeds approximately 2V the device will begin to enter a soft breakdown state. This will show up as reduced input to output isolation. The signal on the non-inverting input of the output driver amplifier will leak through to the inverting input, and then to the output through the feedback resistor. The worst case is a gain of 1 configuration where the non inverting input follows the active input buffer and (through the feedback resistor) the inverting input follows the voltage driving the output stage. The solution for this is to use shutdown mode for multiplexer expansion.

Other Applications

The LMH6574 could support a multi antenna receiver with up to four separate antennas. Monitoring the signal strength of all 4 antennas and connecting the strongest signal to the final IF stage would provide effective spacial diversity.

For direction finding, the LMH6574 could be used to provide high speed sampling of four separate antennas to a single DSP which would use the information to calculate the direction of the received signal.

DRIVING CAPACITIVE LOADS

Capacitive output loading applications will benefit from the use of a series output resistor R_{OUT}. Figure 33 shows the use of a series output resistor, R_{OUT}, to stabilize the amplifier output under capacitive loading. Capacitive loads of 5 to 120 pF are the most critical, causing ringing, frequency response peaking and possible oscillation. The chart Figure 34 gives a recommended value for selecting a series output resistor for mitigating capacitive loads. The values suggested in the charts are selected for 0.5 dB or less of peaking in the frequency response. This gives a good compromise between settling time and bandwidth. For applications where maximum frequency response is needed and some peaking is tolerable, the value of R_{OUT} can be reduced slightly from the recommended values.

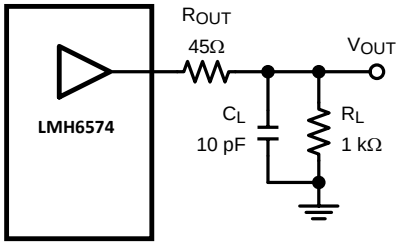


Figure 33. Decoupling Capacitive Loads

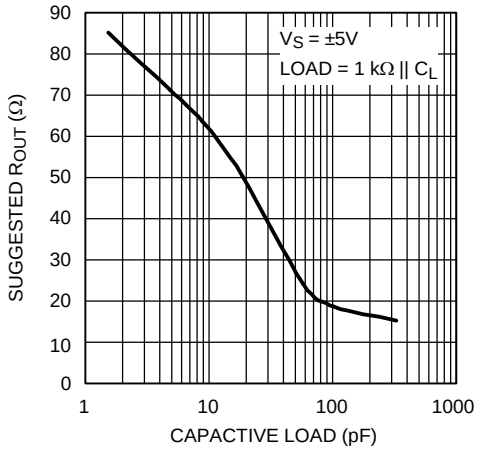


Figure 34. Suggested R_{OUT} vs. Capacitive Load

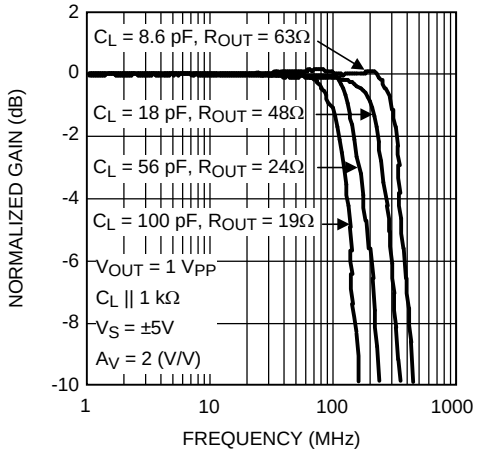


Figure 35. Frequency Response vs. Capacitive Load

LAYOUT CONSIDERATIONS

Whenever questions about layout arise, use the evaluation board as a guide. The LMH730276 is the evaluation board supplied with samples of the LMH6574. To reduce parasitic capacitances, ground and power planes should be removed near the input and output pins. For long signal paths controlled impedance lines should be used, along with impedance matching elements at both ends. Bypass capacitors should be placed as close to the device as possible. Bypass capacitors from each rail to ground are applied in pairs. The larger electrolytic bypass capacitors can be located farther from the device, the smaller ceramic capacitors should be placed as close to the device as possible. In Figure 28, the capacitor between V^+ and V^- is optional, but is recommended for best second harmonic distortion. Another way to enhance performance is to use pairs of 0.01 µF and 0.1 µF ceramic capacitors for each supply bypass.

POWER DISSIPATION

The LMH6574 is optimized for maximum speed and performance in the small form factor of the standard SOIC package. To ensure maximum output drive and highest performance, thermal shutdown is not provided. Therefore, it is of utmost importance to make sure that the T_{JMAX} is never exceeded due to the overall power dissipation.

Follow these steps to determine the Maximum power dissipation for the LMH6574:

1. Calculate the quiescent (no-load) power.

$P_{AMP} = I_{CC}* (V_S)$

where

- $V_S = V^+ - V^-$ (1)

2. Calculate the RMS power dissipated in the output stage:

P_D (rms) = rms $((V_S - V_{OUT}) * I_{OUT})$

where

- V_{OUT} is the voltage across the external load
- I_{OUT} is the current through the external load
- V_S is the total supply voltage (2)

3. Calculate the total RMS power: $P_T = P_{AMP} + P_D$.

The maximum power that the LMH6574 package can dissipate at a given temperature can be derived with the following equation:

$P_{MAX} = (150° – T_{AMB})/ \theta_{JA}$

where

- T_{AMB} = Ambient temperature (°C)
- θ_{JA} = Thermal resistance, from junction to ambient, for a given package (°C/W) (3)

For the SOIC package θ_{JA} is 130 °C/W.

ESD PROTECTION

The LMH6574 is protected against electrostatic discharge (ESD) on all pins. The LMH6574 will survive 2000V Human Body model and 200V Machine model events. Under normal operation the ESD diodes have no effect on circuit performance. There are occasions, however, when the ESD diodes will be evident. If the LMH6574 is driven by a large signal while the device is powered down the ESD diodes will conduct . The current that flows through the ESD diodes will either exit the chip through the supply pins or will flow through the device, hence it is possible to power up a chip with a large signal applied to the input pins. Using the shutdown mode is one way to conserve power and still prevent unexpected operation.

EVALUATION BOARDS

Texas Instruments provides the following evaluation boards as a guide for high frequency layout and as an aid in device testing and characterization. Many of the data sheet plots were measured with this board.

Device	Package	Evaluation Board
LMH6574	SOIC	LMH730276

An evaluation board can be shipped when a sample request is placed with Texas Instruments. Samples can be ordered on the TI web page.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMH6574MA	ACTIVE	SOIC	D	14	55	TBD	Call TI	Call TI	-40 to 85	LMH65 74MA	Samples
LMH6574MA/NOPB	ACTIVE	SOIC	D	14	55	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH65 74MA	Samples
LMH6574MAX	ACTIVE	SOIC	D	14	2500	TBD	Call TI	Call TI	-40 to 85	LMH65 74MA	Samples
LMH6574MAX/NOPB	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMH65 74MA	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

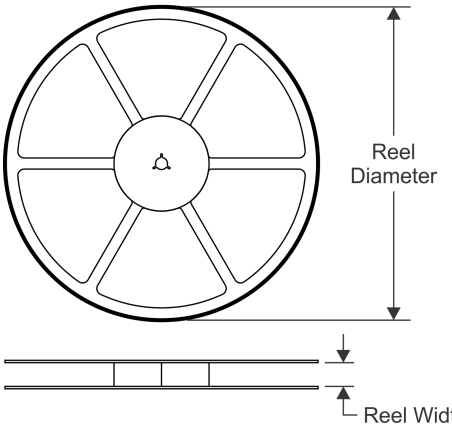
(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

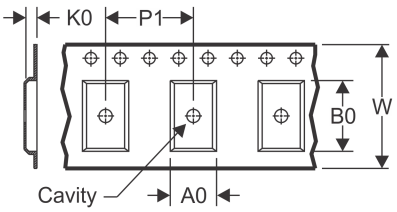
(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

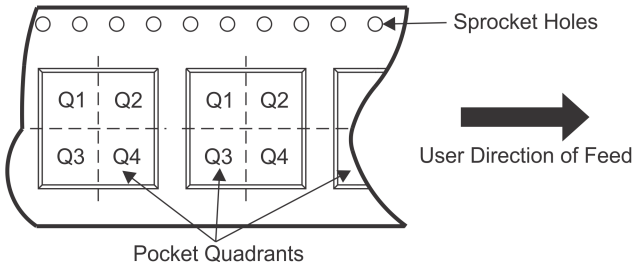


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

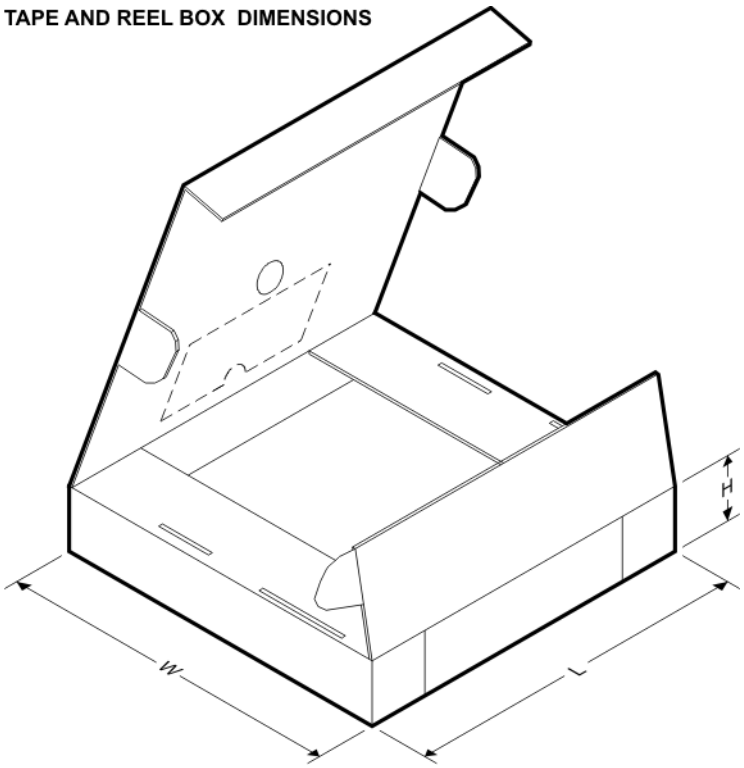
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH6574MAX	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1
LMH6574MAX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1

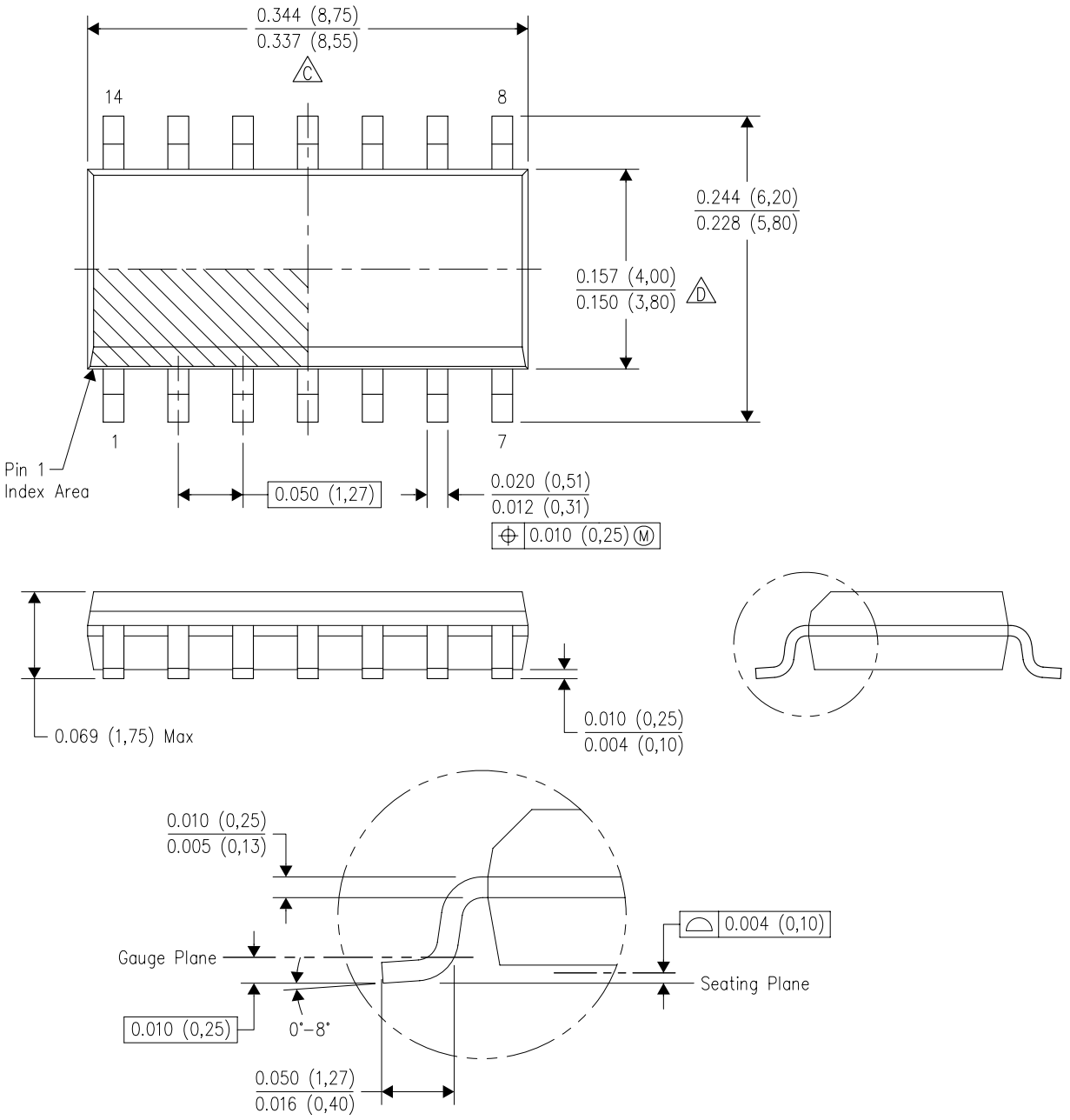
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH6574MAX	SOIC	D	14	2500	367.0	367.0	35.0
LMH6574MAX/NOPB	SOIC	D	14	2500	367.0	367.0	35.0

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



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NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

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